

140 COMMERCE DRIVE **MONTGOMERYVILLE, PA**

18936-1013

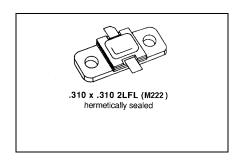
PHONE: (215) 631-9840 FAX: (215) 631-9855

MS2212

RF & MICROWAVE TRANSISTORS AVIONICS APPLICATIONS

Features

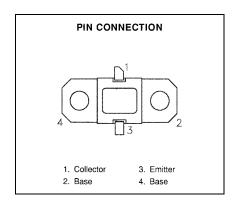
- 960-1215 MHz
- **GOLD METALLIZATION**
- **EMITTER SITE BALLASTED**
- **Pout = 15W**
- Gp = 8.1 dB MINIMUM
- **INTERNAL IMPEDANCE MATCHING**
- **INFINITE VSWR CAPABILITY @ RATED CONDITIONS**
- **COMMON BASE CONFIGURATION**



DESCRIPTION:

The MS2212 is designed for specialized avionics applications, such as JTIDS, where maximum performance is required under a variety of pulse formats. Internal impedance matching provides superior broad band performance.

The MS2212 utilizes gold metallization and emitter ballasting to provide superior reliability and consistent performance under the most rugged pulse conditions.



$(Tcase = 25^{\circ}C)$ ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Collector-Supply Voltage*	32	V
I _C	Device Current*	1.8	Α
P _{DISS}	Power Dissipation*	50	W
T _J	Junction Temperature	+250	°C
T _{STG}	Storage Temperature	- 65 to + 200	°C

Thermal Data

R _{TH(j-c)}	Junction-Case Thermal Resistance*	3.0	°C/W

^{*} Applies only to rated RF operation.



MS2212

ELECTRICAL SPECIFICATIONS (Tcase = 25°C)

STATIC

Cymbol	Test Conditions		Value			Unit	
Symbol		rest Conditions		Min.	Тур.	Max.	Offic
BV _{CBO}	I _C = 10 mA	I _E = 0 mA		55			٧
BV _{CER}	I _C = 10 mA	$R_{BE} = 10 \Omega$		55			V
BV _{EBO}	I _E = 1 mA	I _C = 0 mA		3.5			V
I _{CES}	V _{CE} = 28 V	$V_{BE} = 0 V$				2.0	mA
h _{FE}	V _{CE} = 5 V	I _C = 500mA		15		150	

DYNAMIC

Symbol	Symbol Test Conditions		Value		
Syllibol	rest Conditions	Min.	Тур.	Max.	Unit
P _{OUT}	f = 960 - 1215 MHz P _{IN} = 2.3 W V _{CC} = 28 V	15			W
ης	f = 960 - 1215 MHz P _{IN} = 2.3 W V _{CC} = 28 V	45	49		%
G _P	f = 960 - 1215 MHz P _{IN} = 2.3 W V _{CC} = 28 V	8.1	8.9		dB

Pulse Format: 6.4 μ S on 6.6 μ S off, repeat for 3.3 ms.

Note: Duty Cycle: Burst 49.2%, overall 20.8%

IMPEDANCE DATA:

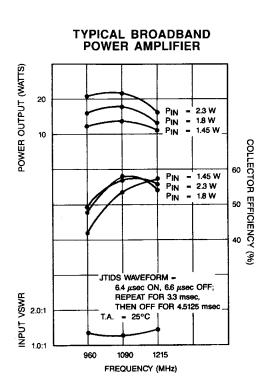
= , (9 = 5,					
FREQUENCY	Zin	ZcI			
960 MHz	5.7 + j4.3	5.7 + j7.7			
1090 MHz	5.8 + j2.5	4.3 + j6.5			
1215 MHz	5.0 + j3.0	4.0 + j4.8			

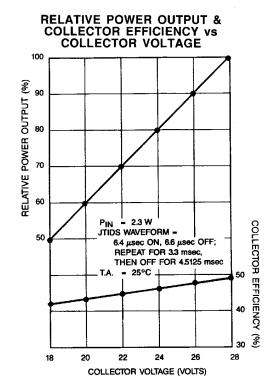
 $P_{IN} = 2.3W$ $V_{CC} = 28V$



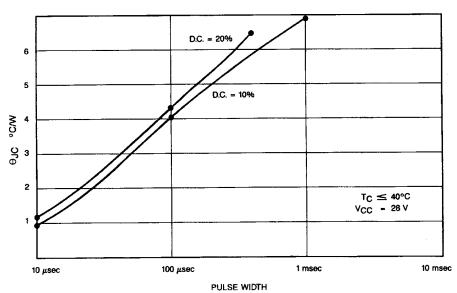


TYPICAL PERFORMANCE





MAXIMUM THERMAL RESISTANCE vs PULSE WIDTH & DUTY CYCLE

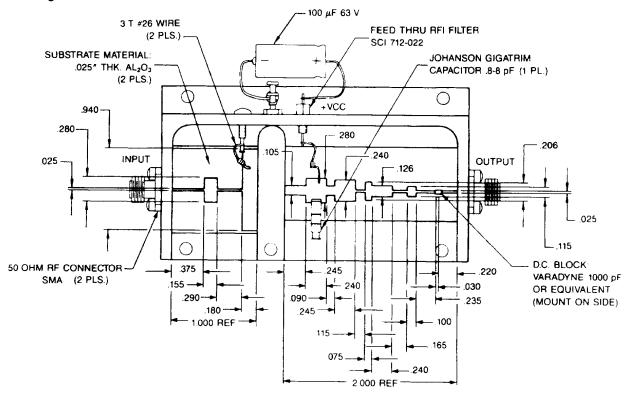






TEST CIRCUIT

Ref.: Dwg. No. 104-000284

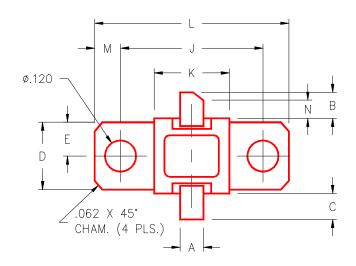


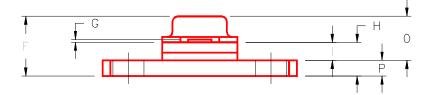




PACKAGE MECHANICAL DATA

PACKAGE STYLE M222





	MINIMUM	MAXIMUM		MINIMUM	MAXIMUM	
	INCHES/MM	INCHES/MM		INCHES/MM	INCHES/MM	
Α	.100/	/2,54	J	.562/14,28		
В	.110/	.110/2,80		.310/7,87		
С	.110/	[/] 2,80	L	.800/20,32		
D	.296/7,52		М	.119/3,02		
Е	.148	/3,76	N	.050/1,27		
F		.230/5,84	0		.170/4,32	
G	.003/0,08	.006/0,15	Р	.062/1,58		
Н	.118/3,00	.131/3,33				
	.059/1,50					